

## High-Reliability Cleaning and Conformal Coating Conference

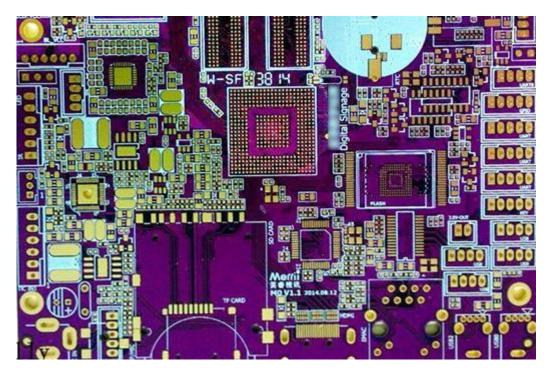
# No-Clean Flux Activity under Low Standoff Components

Bruno Tolla, Ph.D, Jennifer Allen, Kyle Loomis, Denis Jean ~ KESTER Corporation Mike Bixenman, DBA ~ KYZEN Corporation



#### **Electronic Devices**

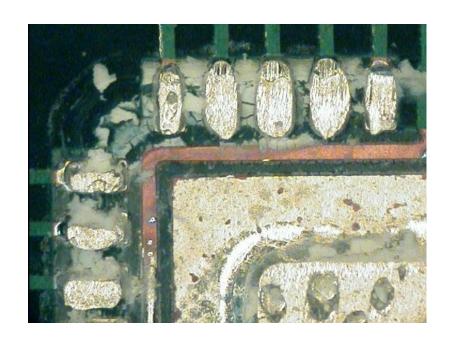
- More complex architectures and larger form factors
- Creates obstacles and challenges for
  - Partial activation
  - Outgassing





## **Leadless Components**

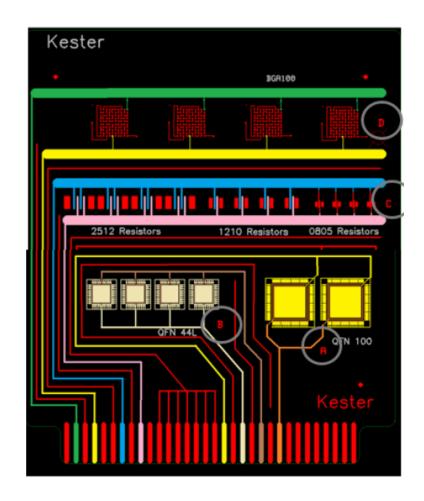
- Low standoff gaps
- High number of interconnects
- Large solder mass under the component termination
- Poor outgassing channels
- Residues trapped under low standoff components
  - May not reach proper activation temperatures
  - No-clean residue may be active





## Research Purpose

- Study the influence of flux activators under low standoff components
  - 4 Activator types
    - Halogen based: Ionic and Covalently bonded
    - Halogen-free: Two Zero-Halogen Packages
  - 2 Reflow conditions
  - 3 Residue cleaning stages
    - Not cleaned / Partially cleaned / Totally cleaned
  - 3 component types
    - BGA 100 (0.8mm pitch)
    - Resistors 2512, 1210, 0805
    - QFN44, QFN100
- Customized test board
  - In-situ SIR measurements under components





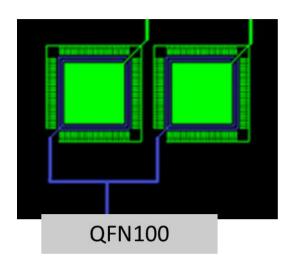


## **EXPERIMENTAL**



## SIR Flux Reliability Test Board

- The IPC SIR test method using the open format B24 pattern directs the user to setup measurement systems to obtain an electrical field strength between the positive and negative traces (gaps) to 5V for 200um of spacing (25V/mm)
- The table below shows a variety of field strengths for the IPC standard boards and the DoE board at different voltage conditions.



Sensor	Gap [mm]	Field Strength [V/mm]			
reference, IPC B24	0.50	25.0			
reference, IPC B25	0.32		31.5		
2512	0.50	25.0	20.0	16.0	10.0
1210	0.34	36.6	29.3	23.4	14.6
0805	0.18	70.3	56.2	45.0	28.1
BGA100	0.35	35.7	28.6	22.9	14.3
MLF441oop-I/O	0.13	93.0	74.4	59.5	37.2
MLF44 loop-center	0.14	91.6	73.2	58.6	36.6
MLF100 loop-I/O	0.29	43.8	35.0	28.0	17.5
MLF100 loop-center	0.29	43.7	35.0	28.0	17.5
Bias Voltage, VDC=		12.5	10	8	5



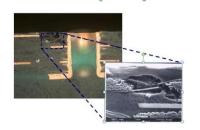
#### No-Clean Solder Pastes

- No-Clean Fluxes
  - Chemical residues left inside the assembly
- Reliability depends on
  - Reactivity of no-clean post-reflow residues
  - Environmental stress

**Corrosion** 



**Conductive Anodic Filaments (CAF)** 

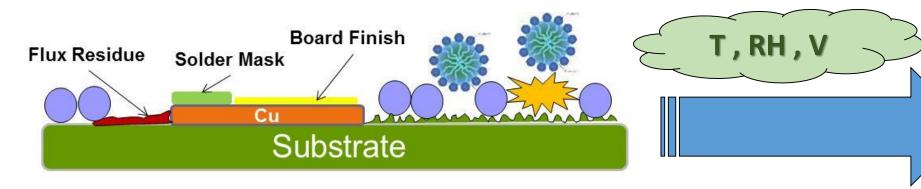


**Electrochemical Migration** 



**Creep Corrosion** 

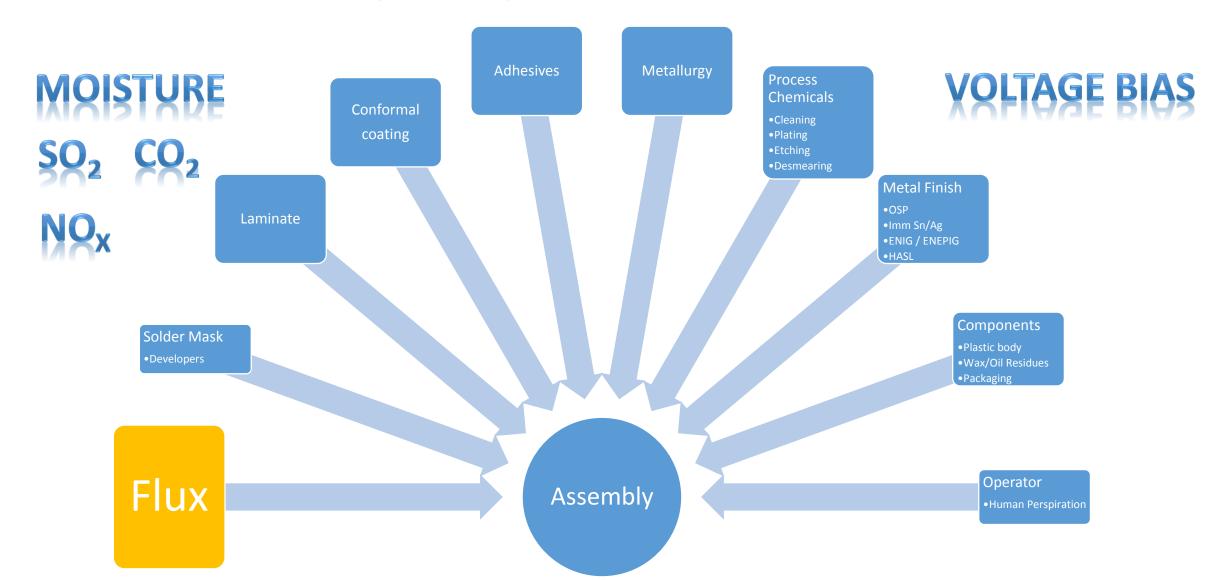








## Chemical Complexity of a PCB







## Flux components



**Restores Metallic** surface

**Promotes Solder Wetting** 

**Oxidation Barrier** 



Solvents Alcohols Water

Remove surface metal oxidation



**Activators** 

Organic acids, Amines, Halogens Fluxes

High T solvent for fluxing byproducts Metal protection

Vehicle Rosin Polyglycols



Thermal conduction Solder Flow







#### SIR Test Parameters

**Test Coupon:** Kester Flux Reliability Test Board

Bias: 8 volts

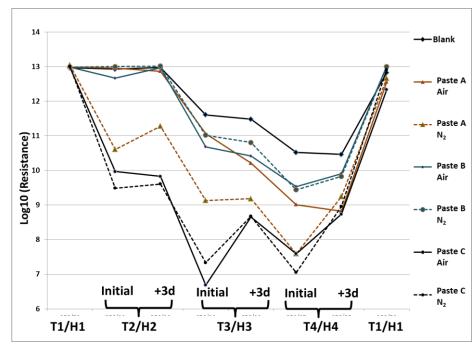
**Test Voltage:** 8 volts

**Temperature:** 85°C

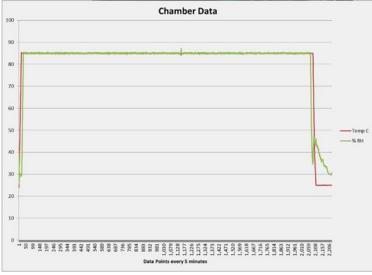
**Humidity:** 85% RH

Measurement Interval: every 20 minutes at condition

**Test Duration:** 7 Days (168 hours)





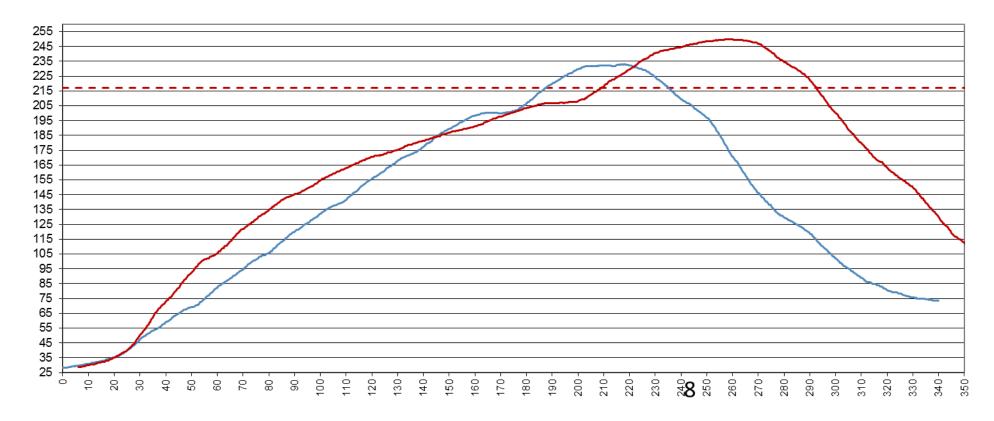


Temperature is ramped before humidity elevated to avoid reaching the dew point. Inverse applies to the recovery ramp down



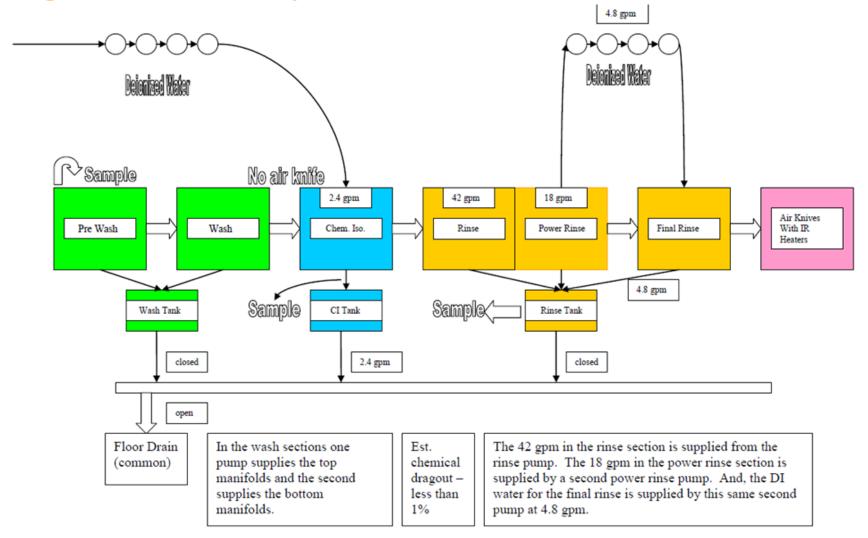
### **Reflow Profiles**

• Two different reflow conditions were used with the intent to subject the flux resides to low and high heating conditions





## **Cleaning Tool Setup**





## **Cleaning Parameters**

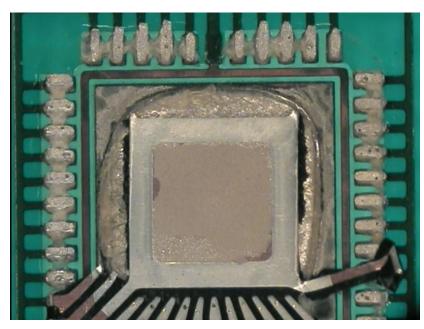
- Cleaning Conditions
  - No-Cleaning
  - Partial Cleaning
    - Inline spray-in-air, 2 FPM, 3 min wash
  - Total Cleaning
    - Inline spray-in-air, 0.5 FPM, 10 minute wash
- Wash Temperature: 65°C
- Subset of parts where removed during setup to assure partial and total cleaning effects

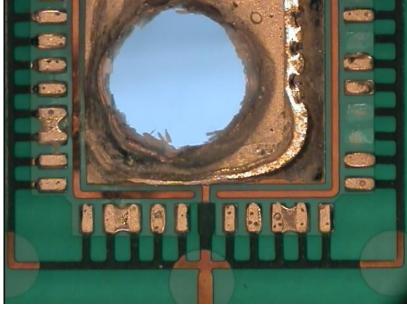


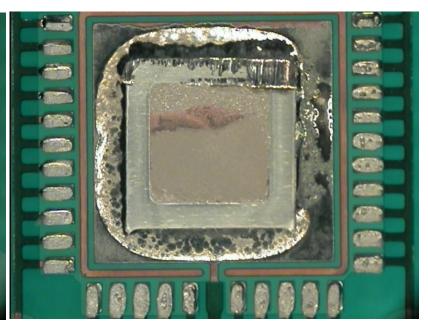
## RESULTS AND DISCUSSION



## Flux Residue







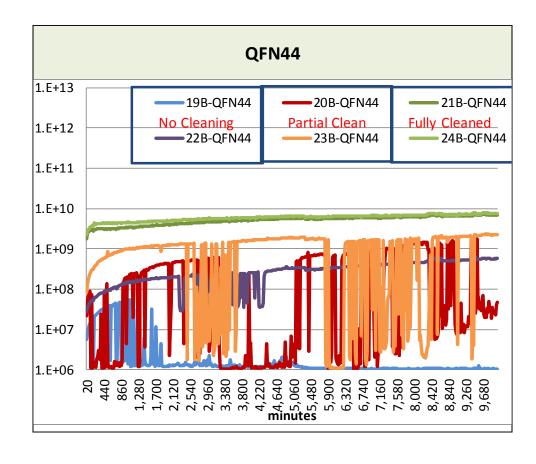
Not Cleaned Partially Cleaned Totally Cleaned



- Halide based solder paste
  - Ionic form of Halogens (R.HCI)
  - Large doping levels (>1,500ppm)

- Worst reliability under components of the four solder pastes tested
  - Chlorine based residues
  - Electrochemical activity independent of reflow conditions

 $CuO + 2HCI = CuCl_2 + H_2O$  $Cu_2O + 2HCI = CuCl_2 + Cu + H_2O$ 

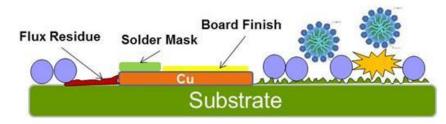




## Reliability fundamentals

Why do halide generate active residues ?





- 1. Highly Ionic
- 2. Environmental interactions
  - Moisture Absorption
  - Hydrolysis
  - Carbonation
- 3. Corrosion of Metallic compounds
  - Oxidation
  - Complexation

 $CuCl_2 + 2H_2O \rightarrow CuCl_2.2H_2O \rightarrow Cu(OH)_2 + 2HCl_2$ 

 $SnCl_2 + 2H_2O \rightarrow Sn(OH)_2 + 2HCI$ 

 $PbCl_2 + CO_2 + H_2O \rightarrow PbCO_3 + 2HCl$ 

$$Cu \rightarrow Cu^+ + e^- [E_0 = 0.52V]$$

$$Cu^+ + Cl^- \rightarrow CuCl [pKs=6.7]$$



 $Cu + Cl \rightarrow CuCl + e^{-}[E_0=0.14V]$ 

Strong Cu complexes catalyze Metal corrosion

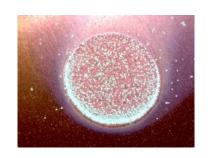


Why do halide generate so active residues ?

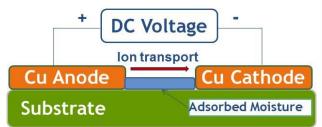
Corrosion



**Electrochemical Migration** 









 $Cu + Cl^{-} \rightarrow CuCl + e^{-} [E_0 = 0.14V]$ 

Strong Cu complexes catalyze metal corrosion

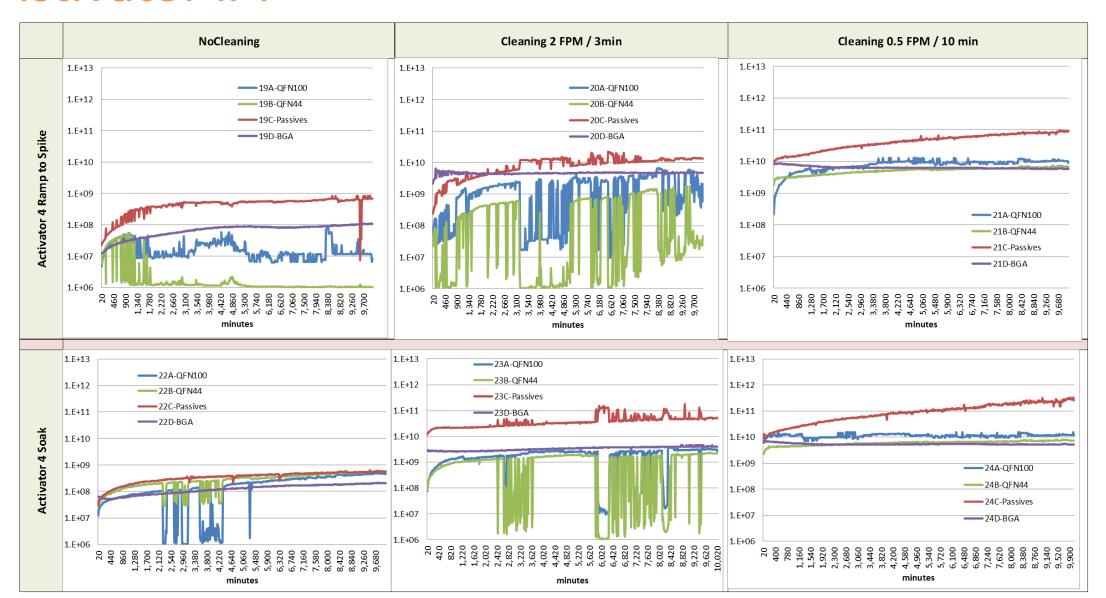
CuCl<sub>2</sub>-, CuCl<sub>3</sub><sup>2</sup>-, CuCl<sub>4</sub><sup>2</sup>-, CuCl<sub>3</sub>-,CuCl<sup>+</sup>

Halides generate a large array of stable complexes





#### **Processing impacts**

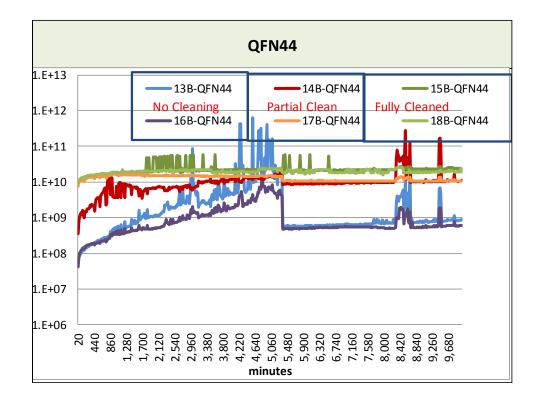




 $CuO + 2HBr \rightarrow CuBr_2 + H_2O$  $Cu_2O + 2HBr = CuBr_2 + Cu + H_2O$ 

- Halogen based solder paste
  - Halogenated Organic Compounds (R-Br)
  - Large doping levels (>1,500ppm)

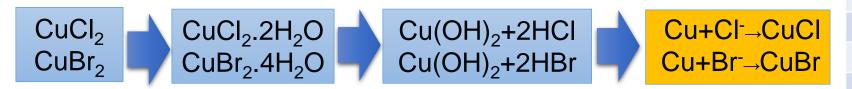
- Best reliability under components of the four solder pastes tested
  - Interplay between processing conditions
    and end use environments





 $CuO + 2HBr \rightarrow CuBr_2 + H_2O$  $Cu_2O + 2HBr = CuBr_2 + Cu + H_2O$ 

- Why did brominated organic components generate safer residues ?
  - Similar Chemistries and physicochemical properties



- Fundamental differences
  - Lower ionicity
  - Halogens are "trapped" in a covalent bond
    - Inert species when unreacted



•	Brominated organic species have much lo	ower	heat
	stability		

Compound	Water solubility (g/100cc)	Color	
CuCl <sub>2</sub>	75.7	Brown	
CuCl	0.006	Green	
CuBr <sub>2</sub>	55.7	Black	
CuBr	Very Slightly	White	
SnCl <sub>2</sub>	83.9	White	
SnBr <sub>2</sub>	85.2	Pale Yellow	
PbCl <sub>2</sub>	1	White	
PbBr <sub>2</sub>	0.8	White	
CuOH <sub>2</sub> / CuCO <sub>3</sub>	Insoluble	Green	





#### **Processing impacts**



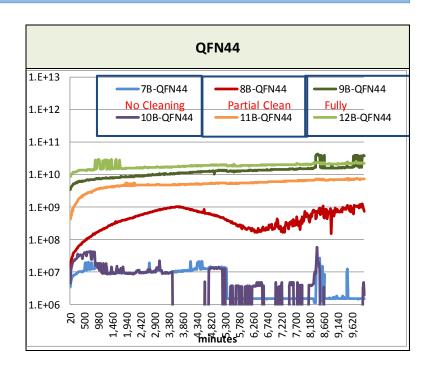


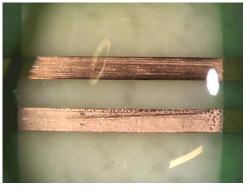
 $CuO + 2RCOOH = Cu(RCOO)_2 + H_2O$  $Cu_2O + 2RCOOH = Cu(RCOO)_2 + Cu + H_2O$ 

- Zero-halogen Solder Paste
  - Substitution of the halogenated activators by a blend of
    - Weak organic acids (RCOOH)
    - Organic amines (RNH<sub>2</sub>, RR'NH, RR'R"N)

- This solder paste had the
  - Worst reliability of the four solder pastes tested in uncleaned conditions

Zero-halogen activator packages can be a source of electrochemical migration









## Reliability Fundamentals



Chemical Impacts on Electrochemical Migration – Zero-Halogen

#### 1. Electrolytic Path formation

Residue hygroscopicity and ionicity

#### 2. Electrodissolution

• Flux corrosiveness

#### 3. Ion Transport

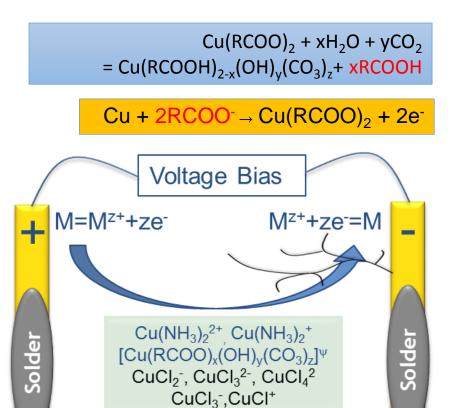
Stabilization of charged complexes

#### 4. Electrodeposition

Complex reduction at the cathode

#### 5. Dendritic Growth

• Diffusion-driven from complex supply



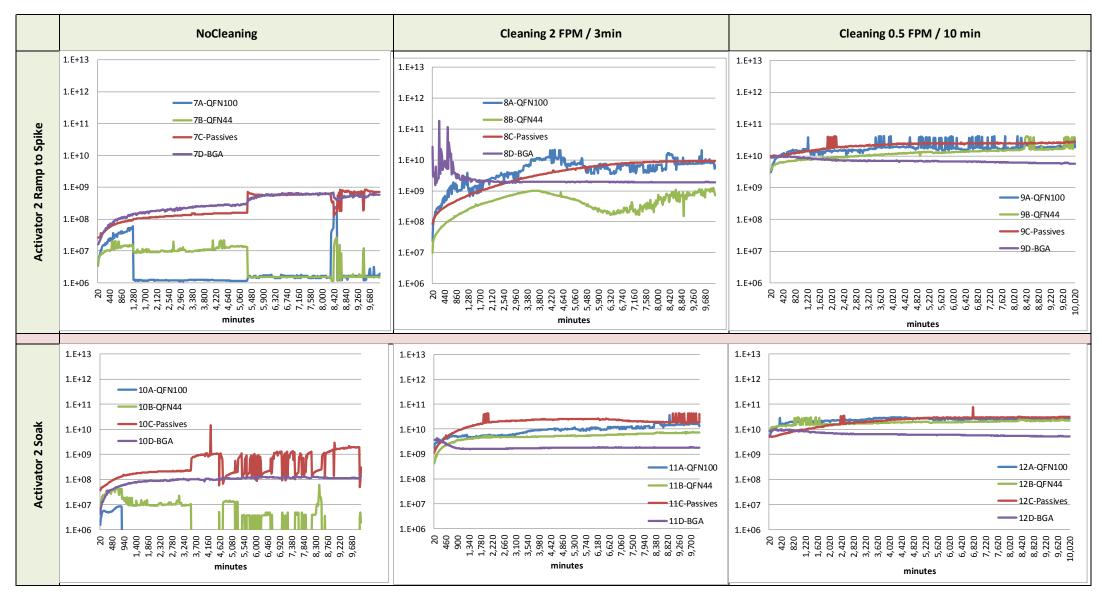
3 Basic ingredients : Moisture, Voltage bias, Ions

 $H_2O = \frac{1}{2}O_2 + 2H^+ + 2e^- \longrightarrow 2H_2O + 2e^- = H_2 + 2OH^-$ 





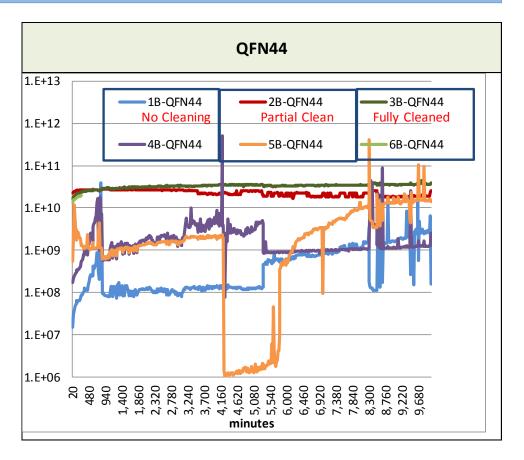
#### **Processing impacts**





 $CuO + 2RCOOH = Cu(RCOO)_2 + H_2O$  $Cu_2O + 2RCOOH = Cu(RCOO)_2 + Cu + H_2O$ 

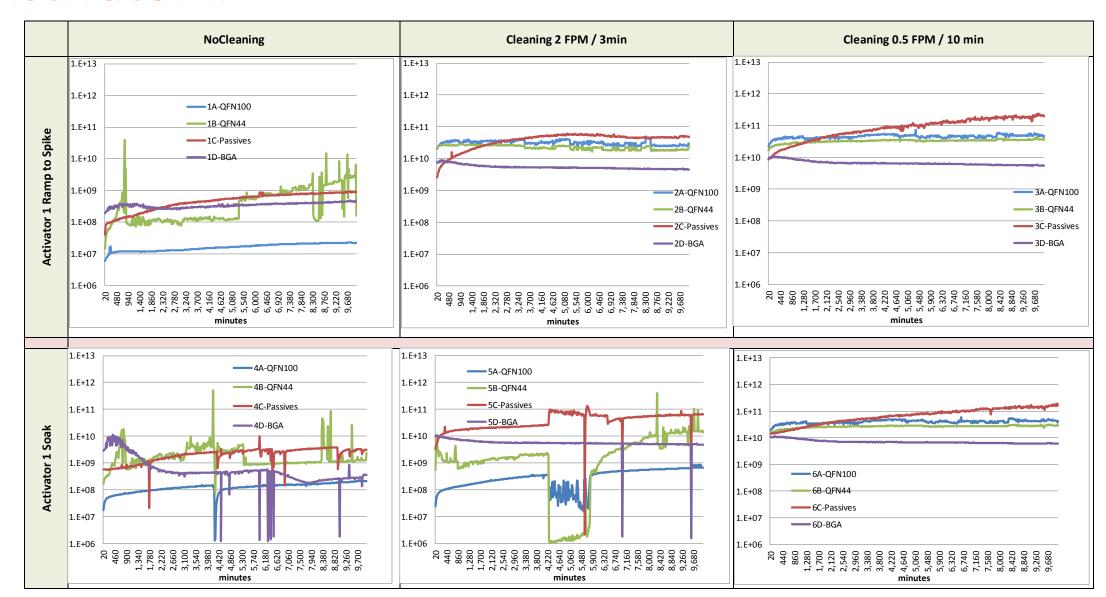
- Zero-Halogen solder paste
  - Optimized blend of:
    - Weak organic acids (RCOOH)
    - Organic amines (RNH<sub>2</sub>, RR'NH, RR'R"N)
    - Corrosion inhibitors / antioxidants
- Significant reliability performance improvement under components compared to Zero-Halogen Activator #2
  - Interplay between processing conditions and end use environments







#### **Processing impacts**







## CONCLUSIONS



#### Flux Activators effects

- Activator types can influence the effect on resistance and current leakage
  - Activator packages are designed to react with metallic oxides but can also induce corrosion and electrochemical migration
- Safe residues requires
  - Hydrophobicity ~ do not attract moisture
  - The "right" chemistry: metal complexation effects
    - A zero-halogen activator package is not a guarantee for reliability
  - Volatilization or decomposition at peak reflow temperatures
    - Eliminate as much as possible active residues



## Components effects

- Four component types tested
  - BGAs showed the highest reliability when residue was present
    - Higher standoff height allowed flux residue to outgas
  - Passive components exhibited some resistivity spikes but for the most part where reliability when residue was present
  - QFNs were not reliable when residue was present
- Outgassing channel
  - A no-clean flux can be active when there is no channel for the flux to outgas



#### **Reflow Profile**

- Most believe that a hotter profile is better for outgassing under low standoff components
  - The data from this study did not show evidence of this effect
- The reflow effect provided interesting findings
  - Zero-halogen activators appear to be more sensitive to reflow conditions
    - Attributed to the thermal instability of activators
  - Halogenated activators
    - Brominated activator showed higher potential to volatilize and outgas
    - Chlorine activator showed electrochemical activity for both soak and ramp-to-spike due to their inherent heat stability



## Cleaning effects

- Partial Cleaning
  - Residue left under the component can be detrimental
  - Some activator types are more problematic than others
  - Similar to partial activation of fluxes: Either you or clean well or you don't
- Total cleaning
  - Improves resistivity values systematically, regardless of the components/chemistries
  - Totally cleaned parts showed good results independent of the activator package
  - Cleaning well can solve the problems of highly active fluxes